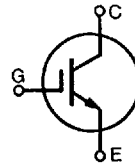


Preliminary data

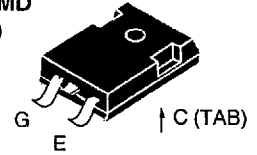
# HiPerFAST™ IGBT

**IXGH24N50B**  
**IXGH24N60B**

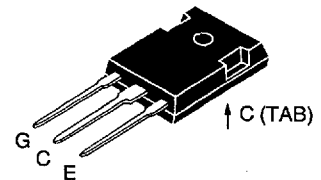
$V_{CES}$	$I_{C(25)}$	$V_{CE(sat)}$	$t_{fi}$
500 V	48 A	2.3 V	80 ns
600 V	48 A	2.5 V	80 ns



TO-247 SMD  
(24N\*\*BS)



TO-247 AD



G = Gate, C = Collector,  
E = Emitter, TAB = Collector

Symbol	Test Conditions	Maximum Ratings		
		24N50	24N60	
$V_{CES}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$	500	600	V
$V_{CGR}$	$T_J = 25^\circ\text{C}$ to $150^\circ\text{C}$ ; $R_{GE} = 1\ \text{M}\Omega$	500	600	V
$V_{GES}$	Continuous		$\pm 20$	V
$V_{GEM}$	Transient		$\pm 30$	V
$I_{C25}$	$T_C = 25^\circ\text{C}$		48	A
$I_{C90}$	$T_C = 90^\circ\text{C}$		24	A
$I_{CM}$	$T_C = 25^\circ\text{C}$ , 1 ms		96	A
<b>SSOA (RBSOA)</b>	$V_{GE} = 15\ \text{V}$ , $T_{VJ} = 125^\circ\text{C}$ , $R_G = 22\ \Omega$ Clamped inductive load, $L = 100\ \mu\text{H}$		$I_{CM} = 48$ @ $0.8\ V_{CES}$	A
$P_C$	$T_C = 25^\circ\text{C}$		150	W
$T_J$		-55 ... +150		$^\circ\text{C}$
$T_{JM}$			150	$^\circ\text{C}$
$T_{stg}$		-55 ... +150		$^\circ\text{C}$
Maximum lead temperature for soldering 1.6 mm (0.062 in.) from case for 10 s			300	$^\circ\text{C}$
$M_d$	Mounting torque (M3)		1.13/10	Nm/lb.in.
Weight			6	g

## Features

- International standard packages JEDEC TO-247 SMD surface mountable and JEDEC TO-247 AD
- High frequency IGBT
- High current handling capability
- 3rd generation HDMOS™ process
- MOS Gate turn-on - drive simplicity

## Applications

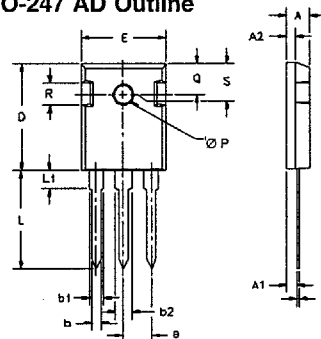
- AC motor speed control
- DC servo and robot drives
- DC choppers
- Uninterruptible power supplies (UPS)
- Switched-mode and resonant-mode power supplies

## Advantages

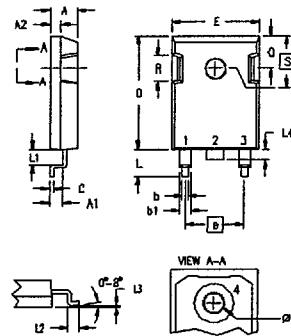
- High power density
- Switching speed for high frequency applications
- Easy to mount with 1 screw (insulated mounting screw hole)

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$BV_{CES}$	$I_C = 250\ \mu\text{A}$ , $V_{GE} = 0\ \text{V}$	24N50	500	V
		24N60	600	V
$V_{GE(th)}$	$I_C = 250\ \mu\text{A}$ , $V_{CE} = V_{GE}$		2.5	5 V
$I_{CES}$	$V_{CE} = 0.8 \cdot V_{CES}$ $V_{GE} = 0\ \text{V}$	$T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$		200 $\mu\text{A}$ 1 mA
$I_{GES}$	$V_{CE} = 0\ \text{V}$ , $V_{GE} = \pm 20\ \text{V}$			$\pm 100\ \text{nA}$
$V_{CE(sat)}$	$I_C = I_{C90}$ , $V_{GE} = 15\ \text{V}$	24N50		2.3 V
		24N60		2.5 V

Symbol	Test Conditions	Characteristic Values ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)		
		min.	typ.	max.
$g_{fs}$	$I_C = I_{C90}$ ; $V_{CE} = 10\text{ V}$ , Pulse test, $t \leq 300\ \mu\text{s}$ , duty cycle $\leq 2\%$	9	13	S
$C_{ies}$	$V_{CE} = 25\text{ V}$ , $V_{GE} = 0\text{ V}$ , $f = 1\text{ MHz}$		1500	pF
$C_{oes}$			135	pF
$C_{res}$			40	pF
$Q_g$	$I_C = I_{C90}$ ; $V_{GE} = 15\text{ V}$ , $V_{CE} = 0.5 V_{CES}$		90	120 nC
$Q_{ge}$			11	15 nC
$Q_{gc}$			30	40 nC
$t_{d(on)}$	<b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b> $I_C = I_{C90}$ ; $V_{GE} = 15\text{ V}$ , $L = 100\ \mu\text{H}$ , $V_{CE} = 0.8 V_{CES}$ ; $R_G = R_{off} = 10\ \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8 \cdot V_{CES}$ , higher $T_J$ , or increased $R_G$		25	ns
$t_{ri}$			15	ns
$E_{on}$			0.6	mJ
$t_{d(off)}$			150	200 ns
$t_{fi}$			80	150 ns
$E_{off}$		24N50B: 0.62 24N60B: 0.80	mJ	
$t_{d(on)}$	<b>Inductive load, <math>T_J = 125^\circ\text{C}</math></b> $I_C = I_{C90}$ ; $V_{GE} = 15\text{ V}$ , $L = 100\ \mu\text{H}$ , $V_{CE} = 0.8 V_{CES}$ ; $R_G = R_{off} = 10\ \Omega$ Remarks: Switching times may increase for $V_{CE}$ (Clamp) $> 0.8 \cdot V_{CES}$ , higher $T_J$ , or increased $R_G$		25	ns
$t_{ri}$			15	ns
$E_{on}$			0.8	mJ
$t_{d(off)}$			250	ns
$t_{fi}$			100	ns
$E_{off}$		24N50B: 0.9 24N60B: 1.4	mJ	
$R_{thJC}$			0.83	K/W
$R_{thCK}$		0.25		K/W

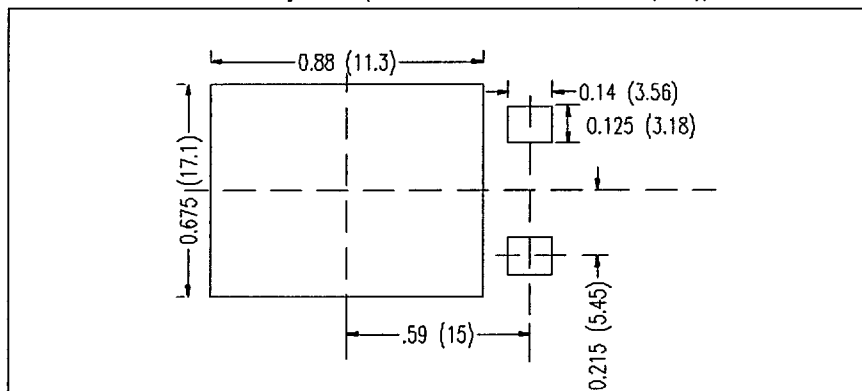
**TO-247 AD Outline**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.7	5.3	.185	.209
A <sub>1</sub>	2.2	2.54	.087	.102
A <sub>2</sub>	2.2	2.6	.059	.098
b	1.0	1.4	.040	.055
b <sub>1</sub>	1.65	2.13	.065	.084
b <sub>2</sub>	2.87	3.12	.113	.123
C	.4	.8	.016	.031
D	20.80	21.46	.819	.845
E	15.75	16.26	.610	.640
e	5.20	5.72	0.205	0.225
L	19.81	20.32	.780	.800
L <sub>1</sub>		4.50		.177
∅P	3.55	3.65	.140	.144
Q	5.89	6.40	0.232	0.252
R	4.32	5.49	.170	.216
S	6.15	BSC	242	BSC

**TO-247 SMD Outline**


1. Gate
2. Collector
3. Emitter
4. Collector

Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.83	5.21	.190	.205
A <sub>1</sub>	2.29	2.54	.090	.100
A <sub>2</sub>	1.91	2.16	.075	.085
b	1.14	1.40	.045	.055
b <sub>1</sub>	1.91	2.13	.075	.084
C	0.61	0.80	.024	.031
D	20.80	21.34	.819	.840
E	15.75	16.13	.620	.635
e	5.45	BSC	.215	BSC
L	4.90	5.10	.193	.201
L <sub>1</sub>	2.70	2.90	.106	.114
L <sub>2</sub>	2.10	2.30	.083	.091
L <sub>3</sub>	0.00	0.10	.00	.004
L <sub>4</sub>	1.90	2.10	.075	.083
∅P	3.55	3.65	.140	.144
Q	5.59	6.20	.220	.244
R	4.32	4.83	.170	.190
S	6.15	BSC	.242	BSC

**Min. Recommended Footprint (Dimensions in inches and (mm))**


IXYS reserves the right to change limits, test conditions, and dimensions.

 IXYS MOSFETS and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715  
 4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025

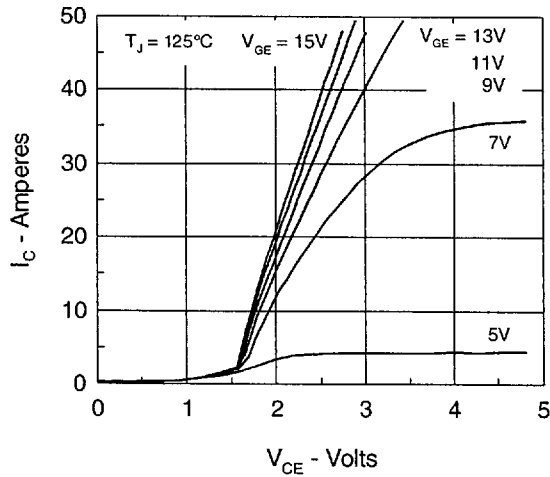


Fig. 1. Saturation Voltage Characteristics

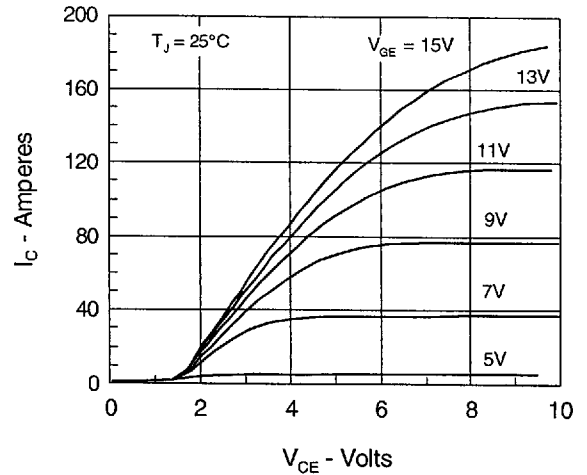


Fig. 2. Extended Output Characteristics

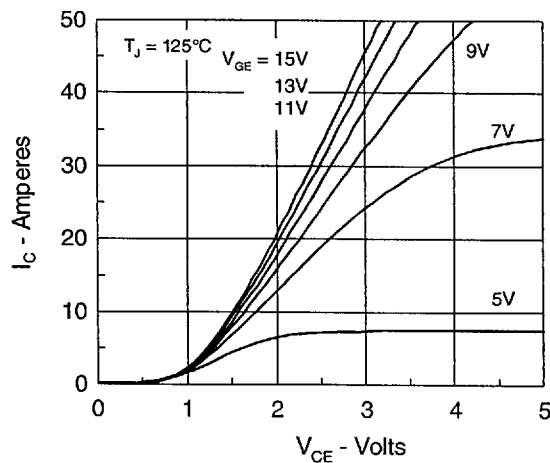


Fig. 3. Saturation Voltage Characteristics

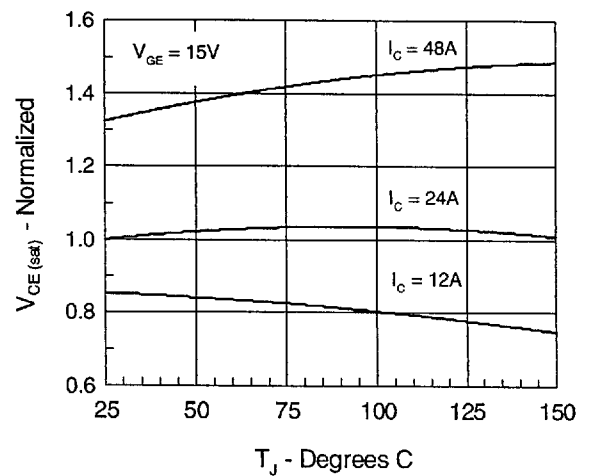


Fig. 4. Temperature Dependence of  $V_{CE(sat)}$

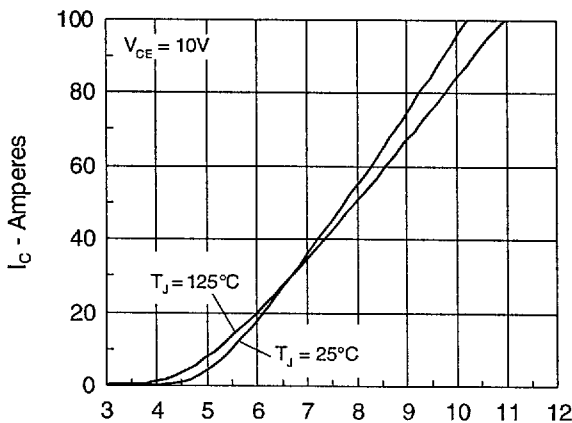


Fig. 5. Admittance Curves

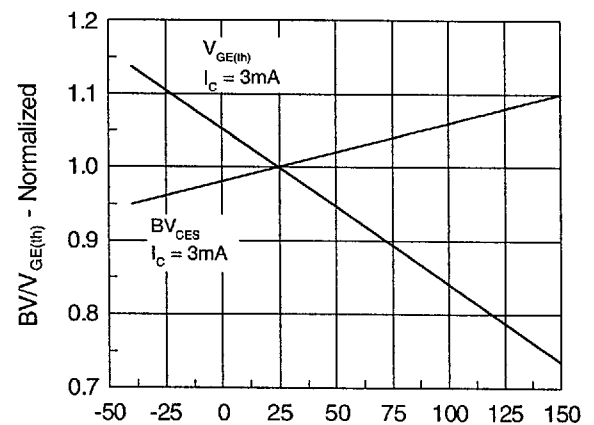


Fig. 6. Temperature Dependence of  $BV_{DSS}$  &  $V_{GE(th)}$

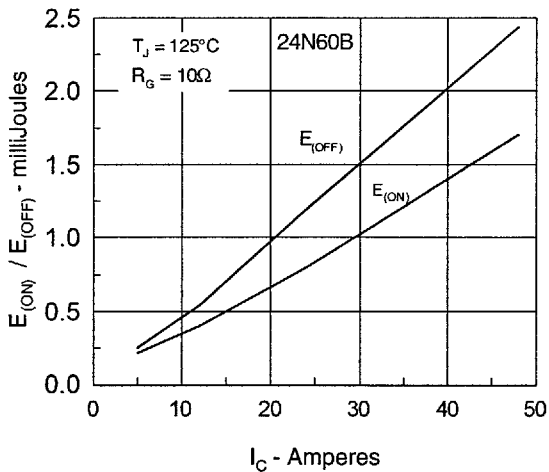


Fig. 7. Dependence of  $t_{fi}$  and  $E_{OFF}$  on  $I_C$ .

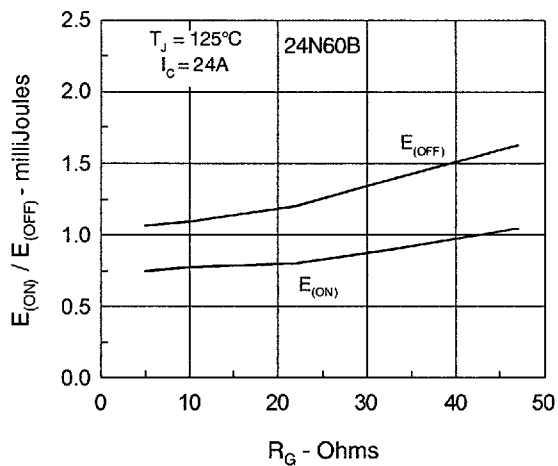


Fig. 8. Dependence of  $t_{fi}$  and  $E_{OFF}$  on  $R_G$ .

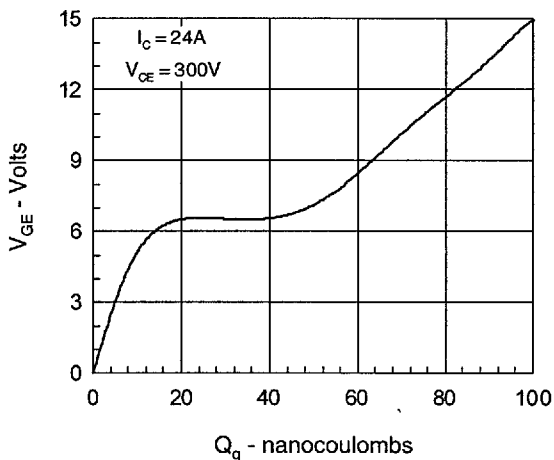


Fig. 9. Gate Charge

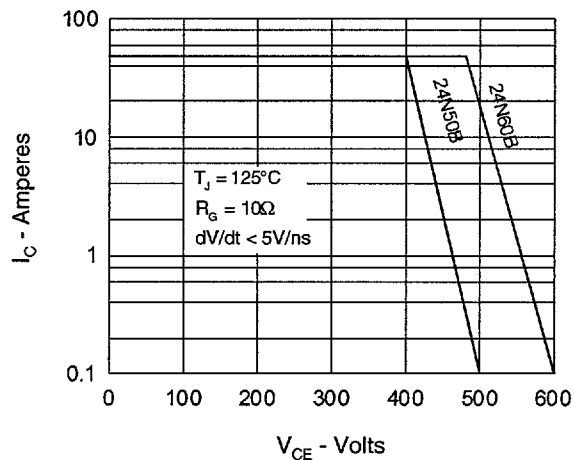


Fig. 10. Turn-off Safe Operating Area

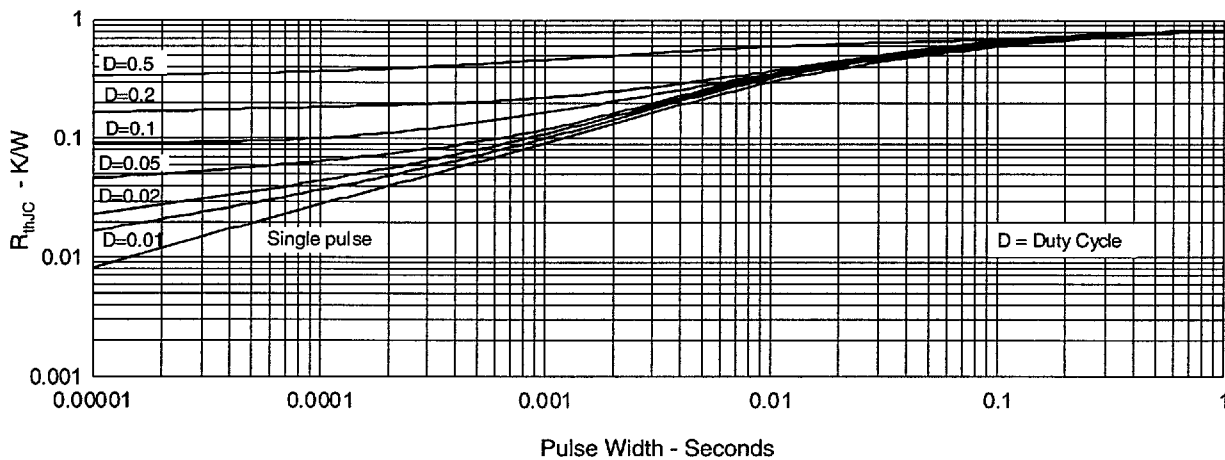


Fig. 11. Transient Thermal Resistance

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4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025